NSN 5961-00-921-8581

Semiconductor Device Set - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-921-8581 **Inclosure Material:** Metal all transistor **Overall Length:** 0.190 inches all transistor **Terminal Length:** 0.500 inches all transistor **Overall Diameter:** 0.219 inches all transistor **Internal Configuration:** Junction contact-darlington connected all transistor Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-18 all transistor **Electrode Internally-electrically Connected To Case:** Collector all transistor **Internal Junction Configuration:** Npn all transistor **Component Function Relationship:** Matched **Component Name And Quantity:** 2 transistor **Mounting Method:** Terminal all transistor **Terminal Circle Diameter:** 0.100 inches all transistor **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 80.0 collector to base voltage, dc all transistor and 60.0 collector to emitter voltage/static/base open all transistor **Current Rating Per Characteristic:** 150.00 milliamperes source cutoff current all transistor **Terminal Type And Quantity:** 3 uninsulated wire lead all transistor Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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